



## Improved Quad SPST CMOS Analog Switches

### FEATURES

- Low On-Resistance: 45  $\Omega$
- Low Power Consumption: 1.0 mW
- Fast Switching Action— $t_{ON}$ : 120 ns
- Low Charge Injection
- TTL/CMOS Logic Compatible

### BENEFITS

- Low Signal Errors and Distortion
- Reduced Power Supply Consumption
- Faster Throughput
- Reduced Pedestal Errors
- Simple Interfacing

### APPLICATIONS

- Audio Switching
- Data Acquisition
- Sample-and-Hold Circuits
- Communication Systems
- Automatic Test Equipment
- Medical Instruments

### DESCRIPTION

The DG444B/445B are monolithic quad analog switches designed to provide high speed, low error switching of analog and audio signals. The DG444B/445B are upgrades to the original DG444/445.

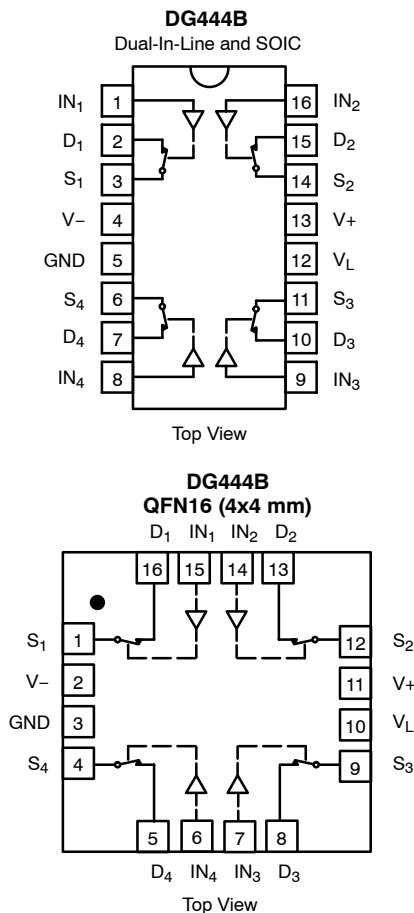
Combining low on-resistance (45  $\Omega$ , typ.) with high speed ( $t_{ON}$  120 ns, typ.), the DG444B/445B are ideally suited for Data Acquisition, Communication Systems, Automatic Test Equipment, or Medical Instrumentation. Charge injection has

been minimized on the drain for use in sample-and-hold circuits.

The DG444B/445B are built using Vishay Siliconix's high-voltage silicon-gate process. An epitaxial layer prevents latchup.

When on, each switch conducts equally well in both directions and blocks input voltages to the supply levels when off.

### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE |        |        |
|-------------|--------|--------|
| Logic       | DG444B | DG445B |
| 0           | ON     | OFF    |
| 1           | OFF    | ON     |

Logic "0"  $\leq 0.8$  V  
Logic "1"  $\geq 2.4$  V

| ORDERING INFORMATION |                    |             |
|----------------------|--------------------|-------------|
| Temp Range           | Package            | Part Number |
| -40 to 85°C          | 16-Pin Plastic DIP | DG444BDJ    |
|                      |                    | DG445BDJ    |
|                      | 16-Pin Narrow SOIC | DG444BDY    |
|                      |                    | DG445BDY    |
|                      | 16-Pin QFN 4x4 mm  | DG444BDN    |
|                      |                    | DG445BDN    |



## ABSOLUTE MAXIMUM RATINGS

|                                                     |                                                                          |
|-----------------------------------------------------|--------------------------------------------------------------------------|
| $V_+$ to $V_-$ .....                                | 44 V                                                                     |
| GND to $V_-$ .....                                  | 25 V                                                                     |
| $V_L$ .....                                         | (GND $-0.3$ V) to ( $V_+$ ) $+0.3$ V                                     |
| Digital Inputs <sup>a</sup> $V_S$ , $V_D$ .....     | ( $V_-$ ) $-2$ V to ( $V_+$ ) $+2$ V<br>or 30 mA, whichever occurs first |
| Continuous Current (Any Terminal) .....             | 30 mA                                                                    |
| Current, S or D (Pulsed 1 ms, 10% duty cycle) ..... | 100 mA                                                                   |
| Storage Temperature .....                           | $-65$ to $125^\circ\text{C}$                                             |

Power Dissipation (Package)<sup>b</sup>

|                                            |        |
|--------------------------------------------|--------|
| 16-Pin Plastic DIP <sup>c</sup> .....      | 470 mW |
| 16-Pin Narrow Body SOIC <sup>d</sup> ..... | 640 mW |
| QFN-16 .....                               | 850 mW |

## Notes:

- Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding  $V_+$  or  $V_-$  will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC Board.
- Derate 6 mW/ $^\circ\text{C}$  above  $75^\circ\text{C}$
- Derate 8 mW/ $^\circ\text{C}$  above  $75^\circ\text{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## SPECIFICATIONS FOR DUAL SUPPLIES

| Parameter                                   | Symbol              | Test Conditions<br>Unless Otherwise Specified<br><br>V <sub>+</sub> = 15 V, V <sub>-</sub> = -15 V<br>V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>e</sup> | Temp <sup>a</sup> | Limits<br>-40 to 85°C |                  |                  | Unit |
|---------------------------------------------|---------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|-----------------------|------------------|------------------|------|
|                                             |                     |                                                                                                                                                                         |                   | Min <sup>b</sup>      | Typ <sup>c</sup> | Max <sup>b</sup> |      |
| Analog Switch                               |                     |                                                                                                                                                                         |                   |                       |                  |                  |      |
| Analog Signal Range <sup>d</sup>            | V <sub>ANALOG</sub> |                                                                                                                                                                         | Full              | -15                   |                  | 15               | V    |
| Drain-Source On-Resistance                  | r <sub>DS(on)</sub> | I <sub>S</sub> = 1 mA, V <sub>D</sub> =    ±10 V                                                                                                                        | Room<br>Full      |                       | 45               | 80<br>95         | Ω    |
| Switch Off Leakage Current                  | I <sub>S(off)</sub> | V <sub>D</sub> =    ±14 V, V <sub>S</sub> =    ±14 V                                                                                                                    | Room<br>Full      | -0.5<br>-5            | ±0.01            | 0.5<br>5         | nA   |
|                                             | I <sub>D(off)</sub> |                                                                                                                                                                         | Room<br>Full      | -0.5<br>-5            | ±0.01            | 0.5<br>5         |      |
| Channel On Leakage Current                  | I <sub>D(on)</sub>  | V <sub>S</sub> = V <sub>D</sub> =    ±14 V                                                                                                                              | Room<br>Full      | -0.5<br>-10           | ±0.02            | 0.5<br>10        |      |
| Digital Control                             |                     |                                                                                                                                                                         |                   |                       |                  |                  |      |
| Input Voltage Low                           | V <sub>INL</sub>    |                                                                                                                                                                         | Full              |                       |                  | 0.8              | V    |
| Input Voltage High                          | V <sub>INH</sub>    |                                                                                                                                                                         | Full              | 2.4                   |                  |                  |      |
| Input Current V <sub>IN</sub> Low           | I <sub>INL</sub>    | V <sub>IN</sub> under test = 0.8 V, All Other = 2.4 V                                                                                                                   | Full              | -1                    | -0.01            | 1                | μA   |
| Input Current V <sub>IN</sub> High          | I <sub>INH</sub>    | V <sub>IN</sub> under test = 2.4 V, All Other = 0.8 V                                                                                                                   | Full              | -1                    | 0.01             | 1                |      |
| Dynamic Characteristics                     |                     |                                                                                                                                                                         |                   |                       |                  |                  |      |
| Turn-On Time                                | t <sub>ON</sub>     | R <sub>L</sub> = 1 kΩ, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = ±10 V, See Figure 2                                                                                   | Room              |                       |                  | 300              | ns   |
| Turn-Off Time                               | t <sub>OFF</sub>    |                                                                                                                                                                         | Room              |                       |                  | 200              |      |
| Charge Injection <sup>e</sup>               | Q                   | C <sub>L</sub> = 1 nF, V <sub>S</sub> = 0 V<br>V <sub>gen</sub> = 0 V, R <sub>gen</sub> = 0 Ω                                                                           | Room              |                       | 1                |                  | pC   |
| Off Isolation <sup>e</sup>                  | OIRR                | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 15 pF, V <sub>S</sub> = 1 V <sub>RMS</sub><br>f = 100 kHz                                                                       | Room              |                       | 90               |                  | dB   |
| Crosstalk (Channel-to-Channel) <sup>d</sup> | X <sub>TALK</sub>   |                                                                                                                                                                         | Room              |                       | 95               |                  |      |
| Source Off Capacitance                      | C <sub>S(off)</sub> | V <sub>S</sub> = 0 V, f = 100 kHz                                                                                                                                       | Room              |                       | 5                |                  | pF   |
| Drain Off Capacitance                       | C <sub>D(off)</sub> |                                                                                                                                                                         | Room              |                       | 5                |                  |      |
| Channel On Capacitance                      | C <sub>D(on)</sub>  | V <sub>S</sub> V <sub>D</sub> = 0 V, f = 1 MHz                                                                                                                          | Room              |                       | 16               |                  |      |
| Power Supplies                              |                     |                                                                                                                                                                         |                   |                       |                  |                  |      |
| Positive Supply Current                     | I <sub>+</sub>      | V <sub>IN</sub> = 0 or 5 V                                                                                                                                              | Room<br>Full      |                       |                  | 1<br>5           | μA   |
| Negative Supply Current                     | I <sub>-</sub>      |                                                                                                                                                                         | Room<br>Full      | -1<br>-5              |                  |                  |      |
| Logic Supply Current                        | I <sub>IN</sub>     |                                                                                                                                                                         | Room<br>Full      |                       |                  | 1<br>5           |      |



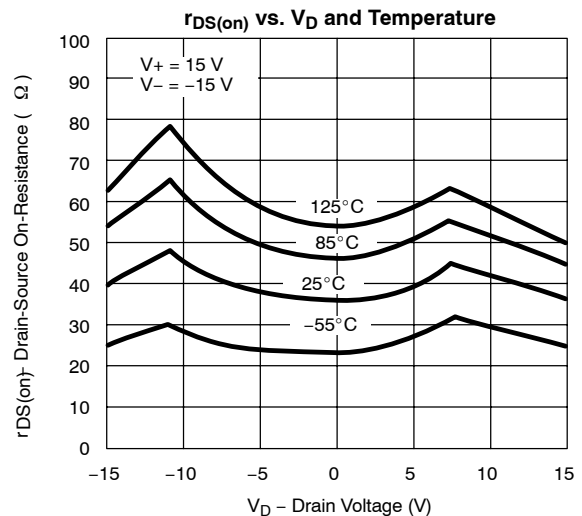
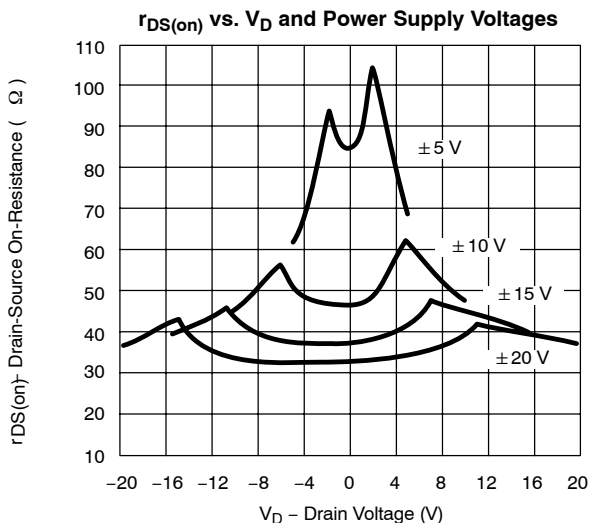
## SPECIFICATIONS FOR UNIPOLAR SUPPLIES

| Parameter                               | Symbol              | Test Conditions<br>Unless Otherwise Specified<br><br>V <sub>+</sub> = 12 V, V <sub>-</sub> = 0 V<br>V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>e</sup> | Temp <sup>a</sup> | D Suffix<br>-40 to 85°C |                  |                  | Unit |
|-----------------------------------------|---------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|-------------------------|------------------|------------------|------|
|                                         |                     |                                                                                                                                                                       |                   | Min <sup>b</sup>        | Typ <sup>c</sup> | Max <sup>b</sup> |      |
| Analog Switch                           |                     |                                                                                                                                                                       |                   |                         |                  |                  |      |
| Analog Signal Range <sup>d</sup>        | V <sub>ANALOG</sub> |                                                                                                                                                                       | Full              | 0                       |                  | 12               | V    |
| Drain-Source On-Resistance <sup>d</sup> | r <sub>DS(on)</sub> | I <sub>S</sub> = 1 mA, V <sub>D</sub> = 3 V, 8 V                                                                                                                      | Room<br>Full      |                         | 90               | 160<br>200       | Ω    |
| Dynamic Characteristics                 |                     |                                                                                                                                                                       |                   |                         |                  |                  |      |
| Turn-On Time                            | t <sub>ON</sub>     | R <sub>L</sub> = 1 kΩ, C <sub>L</sub> = 35 pF, V <sub>S</sub> = 8 V<br>See Figure 2                                                                                   | Room              |                         | 120              | 300              | ns   |
| Turn-Off Time                           | t <sub>OFF</sub>    |                                                                                                                                                                       | Room              |                         | 60               | 200              |      |
| Charge Injection                        | Q                   | C <sub>L</sub> = 1 nF, V <sub>gen</sub> = 6 V, R <sub>gen</sub> = 0 Ω                                                                                                 | Room              |                         | 4                |                  | pC   |
| Power Supplies                          |                     |                                                                                                                                                                       |                   |                         |                  |                  |      |
| Positive Supply Current                 | I <sub>+</sub>      | V <sub>IN</sub> = 0 or 5 V                                                                                                                                            | Room<br>Full      |                         |                  | 1<br>5           | μA   |
| Negative Supply Current                 | I <sub>-</sub>      |                                                                                                                                                                       | Room<br>Full      | -1<br>-5                |                  |                  |      |
| Logic Supply Current                    | I <sub>IN</sub>     | V <sub>L</sub> = 5.25 V, V <sub>IN</sub> = 0 or 5 V                                                                                                                   | Room<br>Full      |                         |                  | 1<br>5           |      |

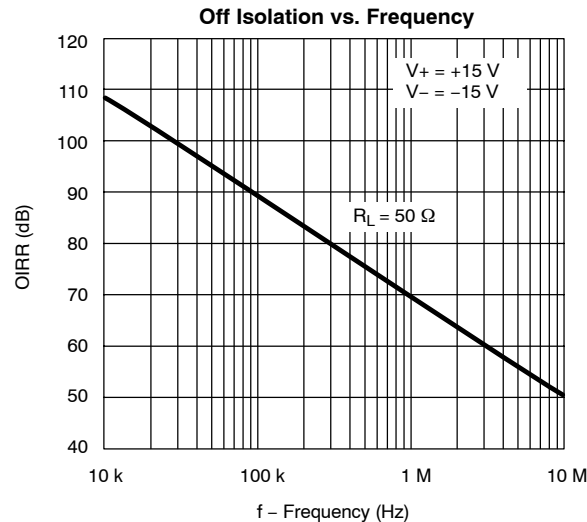
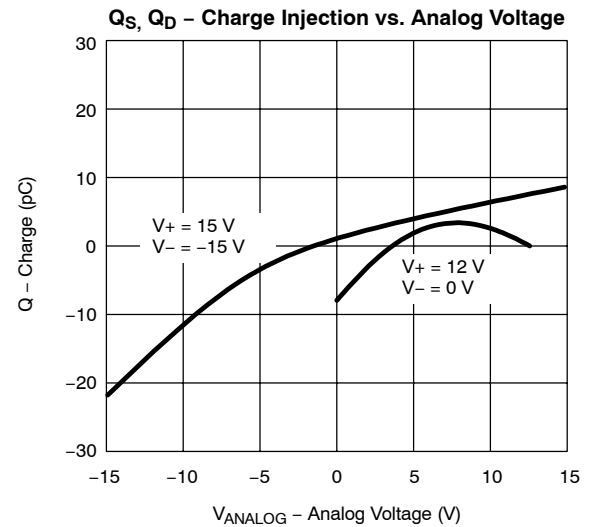
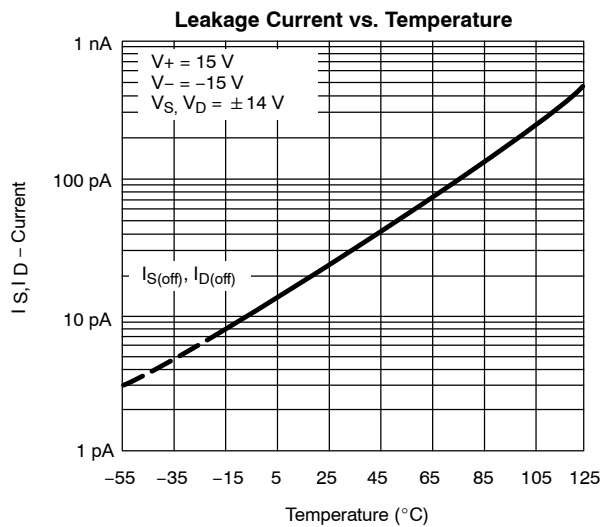
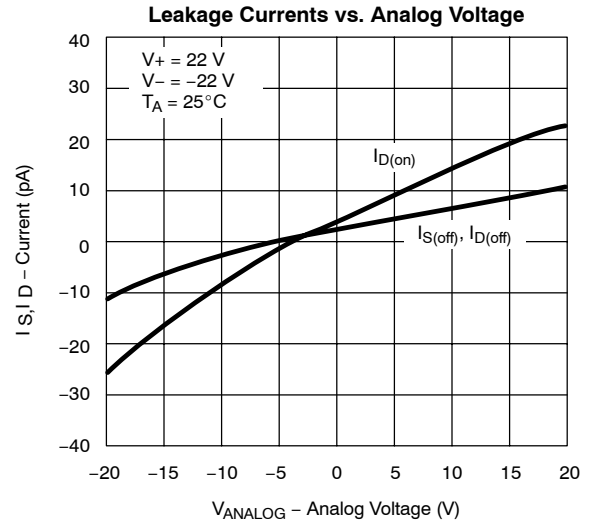
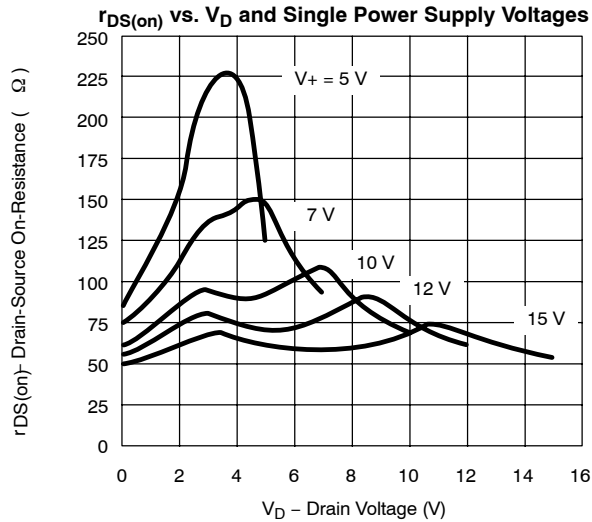
## Notes:

- Room = 25°C, Full = as determined by the operating temperature suffix.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- Guaranteed by design, not subject to production test.
- $V_{IN}$  = input voltage to perform proper function.

## TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**



**SCHEMATIC DIAGRAM (TYPICAL CHANNEL)**

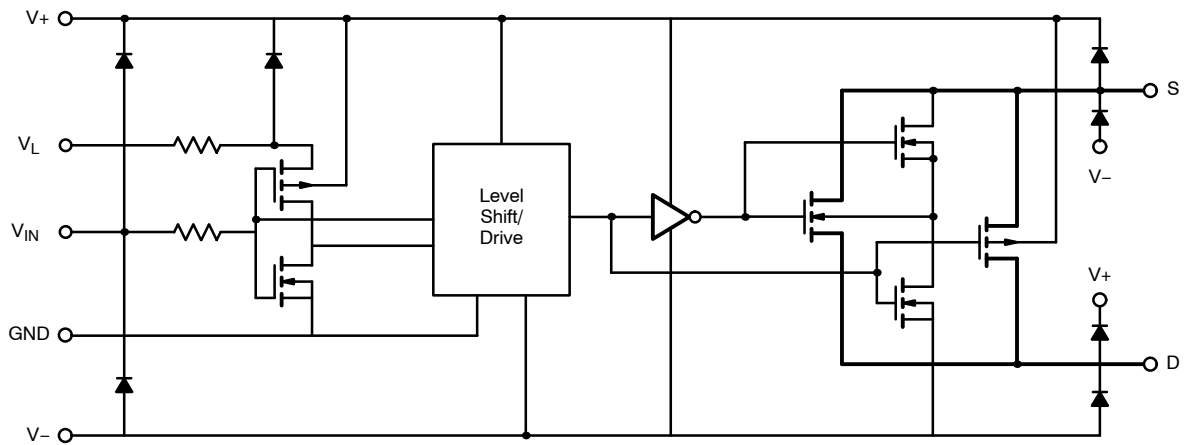
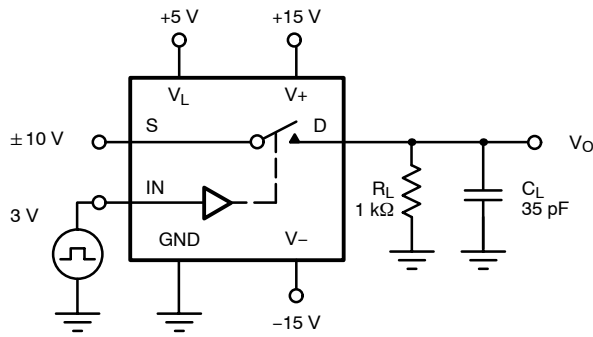
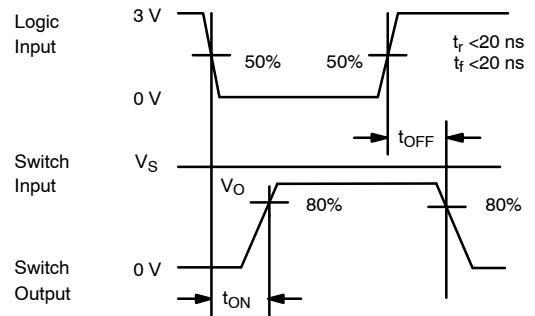


FIGURE 1.

**TEST CIRCUITS**



$C_L$  (includes fixture and stray capacitance)



Note: Logic input waveform is inverted for DG445.

FIGURE 2. Switching Time

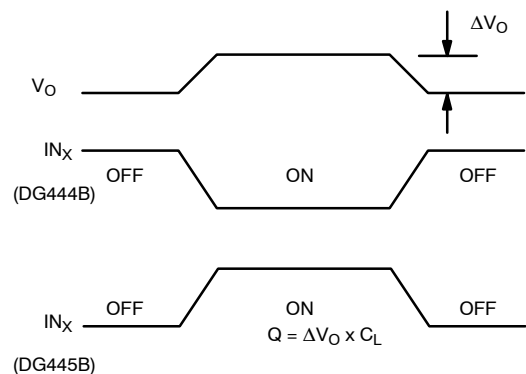
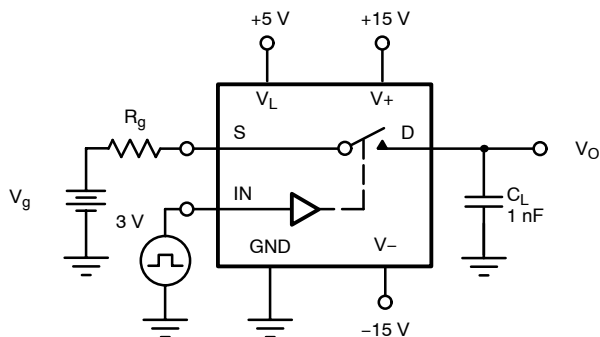


FIGURE 3. Charge Injection



TEST CIRCUITS

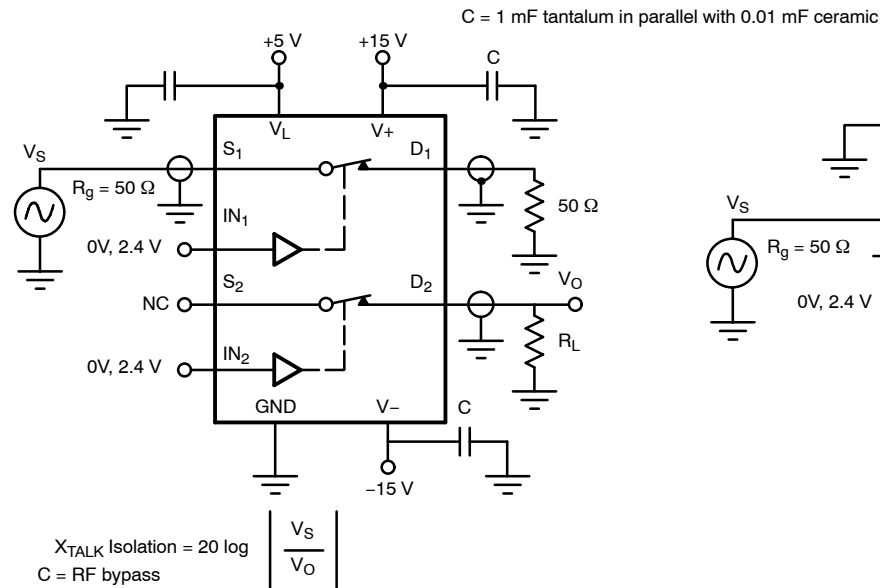


FIGURE 4. Crosstalk

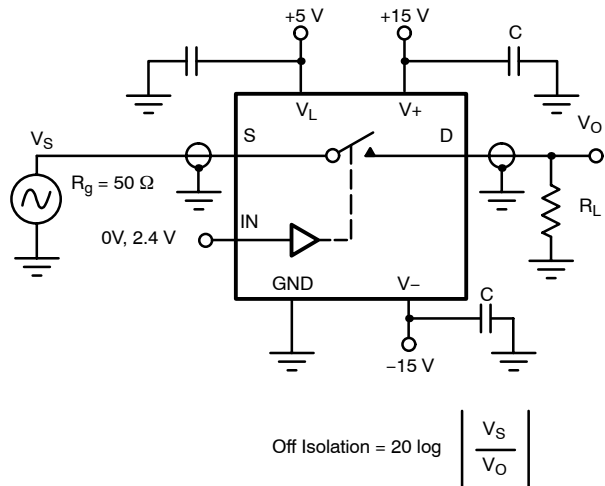


FIGURE 5. Off Isolation

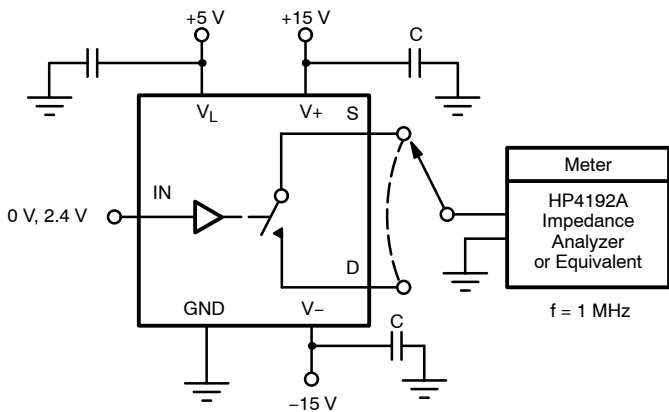


FIGURE 6. Source/Drain Capacitances

APPLICATIONS

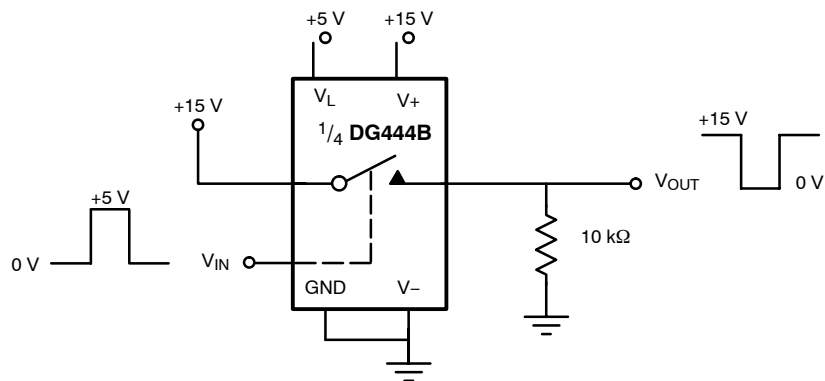
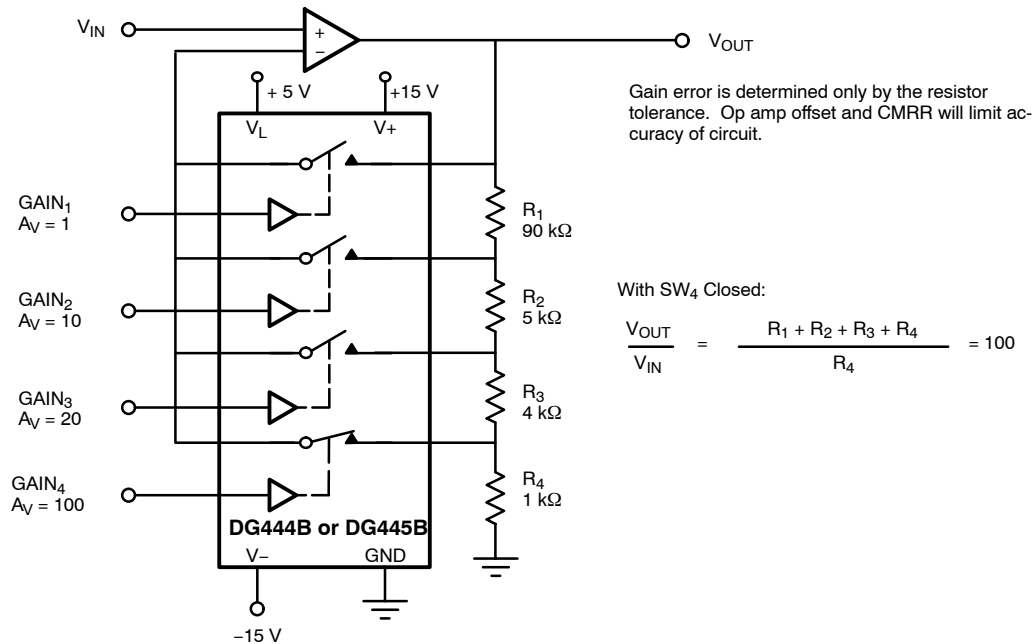
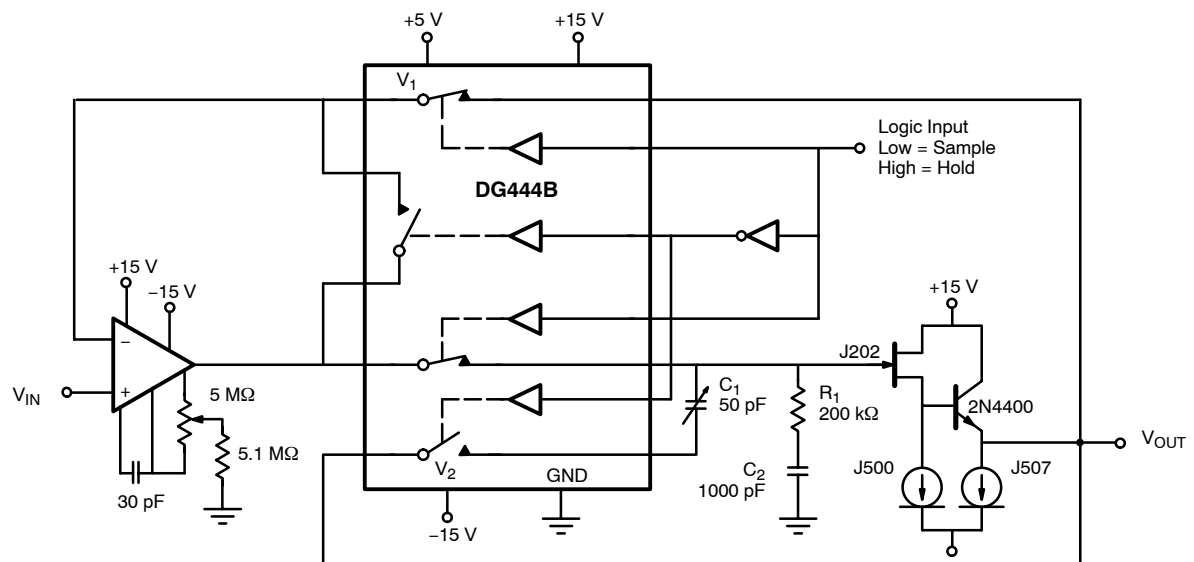


FIGURE 7. Level Shifter

## APPLICATIONS



**FIGURE 8.** Precision-Weighted Resistor Programmable-Gain Amplifier



**FIGURE 9.** Precision Sample-and-Hold